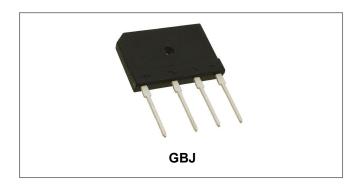


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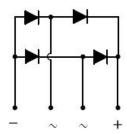
GBJ2510-A Single-Phase 25.0A Glass Passivated Bridge Rectifier



Features

- · Glass passivated die construction
- · Low forward voltage drop
- High current capability
- High surge current capability
- Plastic material-UL flammability 94V-0
- "-A" is an AEC-Q101 qualified device
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- Case: GBJ, Molded plastic
- Terminals: Plated leads solderable per MIL-STD-202, Method 208
- Polarity: as marked on case
- Mounting Position: Any
- Lead Free: For RoHS / Lead Free Version

Maximum Ratings @TA=25°C unless otherwise specified

| Type Number | Symbol | GBJ2510-A | Units |
|---|---|-----------------------|-------|
| Marking Code | | GBJ2510 | |
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _{DC} | V _{RWM} 1000 | |
| RMS Reverse Voltage | V _{RMS} | 700 | |
| Average forward rectified output current @T _A =100°C | I _(AV) | 25.0 | |
| Peak Forward Surge Current,8.3ms single half- sine-wave superimposed on rated load (JEDEC method) | I _{FSM} | 300 | А |

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Electrical Characteristics@TA=25°C unless otherwise specified

| Type Number | Symbol | GBJ2510-A | Units |
|---|-----------------|-------------|-------|
| Forward Voltage (per element) @I _F =12.5A @I _F =25A | V _F | 1.0 1.1 | V |
| Peak Reverse Current @T _A = 25°C At Rated DC Blocking Voltage @T _A = 125°C | I _{RM} | 10.0 500 | μА |
| Typical Junction Capacitance(per leg) (Note 1) | CJ | 85 | pF |

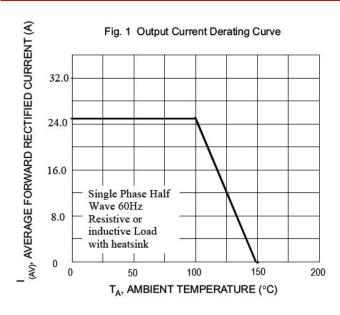
^{*} Pulse width < 300 μs, duty cycle < 2%

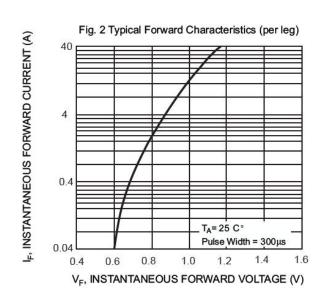
Thermal-Mechanical Specifications:

| Type Number | Symbol | GBJ2510-A | Units |
|---|--------------------------------------|-------------|-------|
| Between Junction and Ambient, Without heatsink Between Junction and Case, Without heatsink | R _{θJA} R _{θJc} | 22 1.0 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

Note: 1- Measured at 1 MHZ and applied reverse voltage of 4.0 VDC.

Ratings and Characteristics Curves

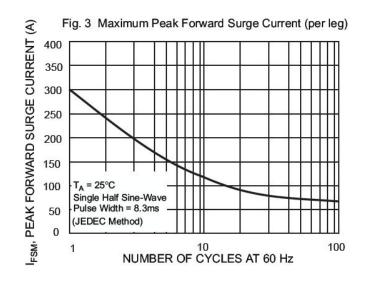


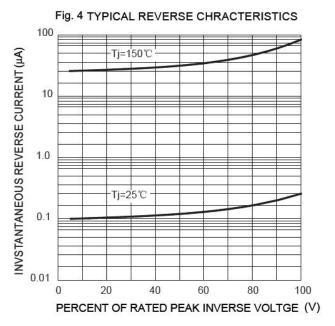


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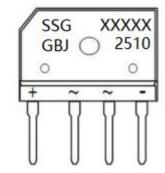


Ordering Information

| Device | Package | Plating | Shipping |
|-----------|------------------|---------|--------------|
| GBJ2510-A | GBJ (Pb-Free) | Pure Sn | 15pcs / tube |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

 GBJ2510
 = Type Number

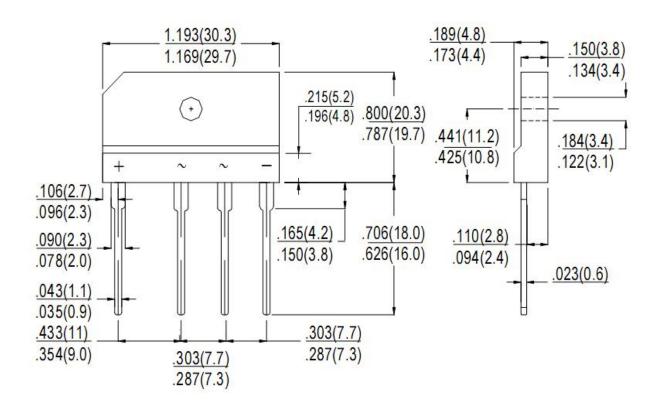
Cautions: Molding resin Epoxy resin UL:94V-0

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Mechanical Dimensions GBJ (Inches/Millimeters)



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